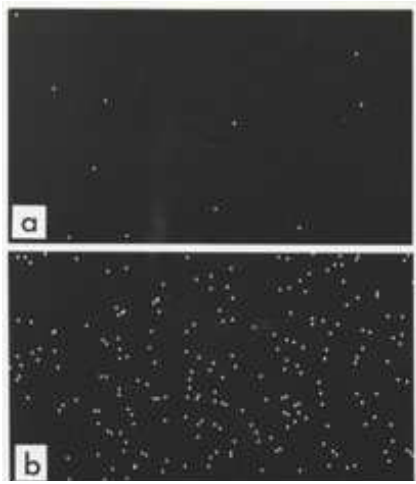
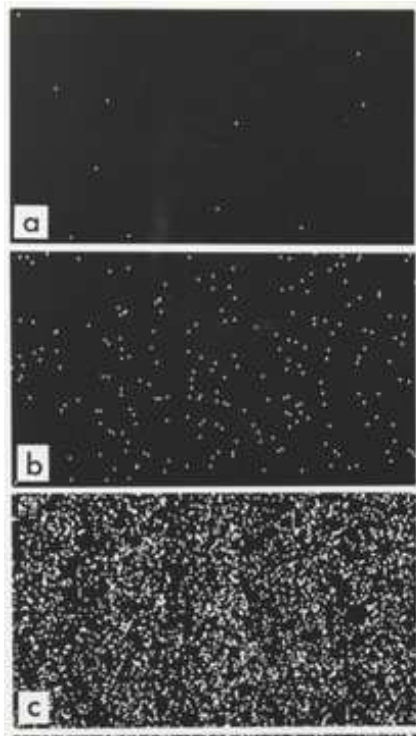


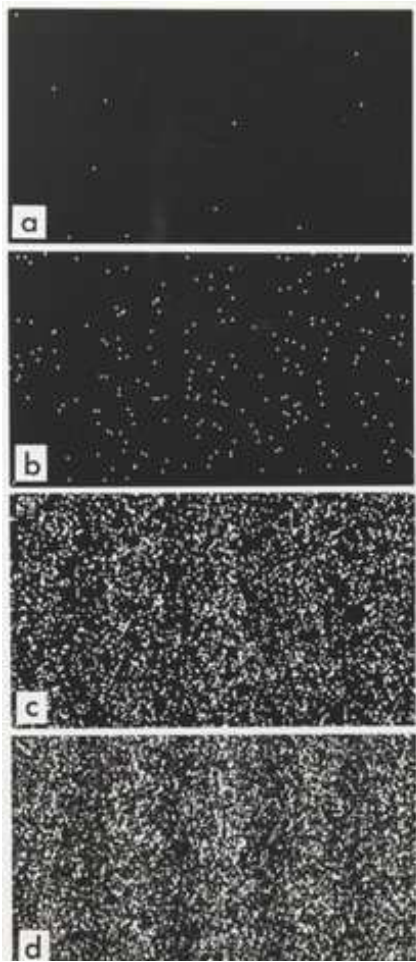
“Shot Noise”

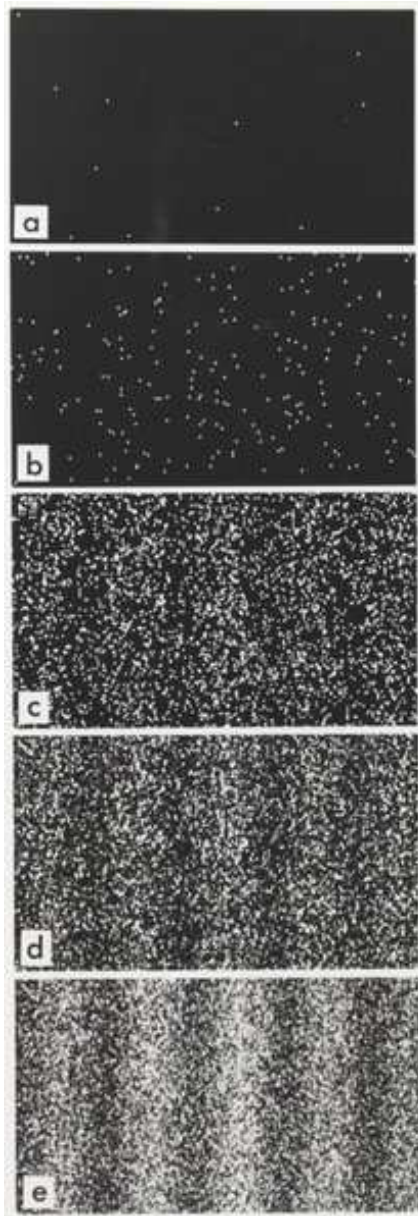
G. Gallatin









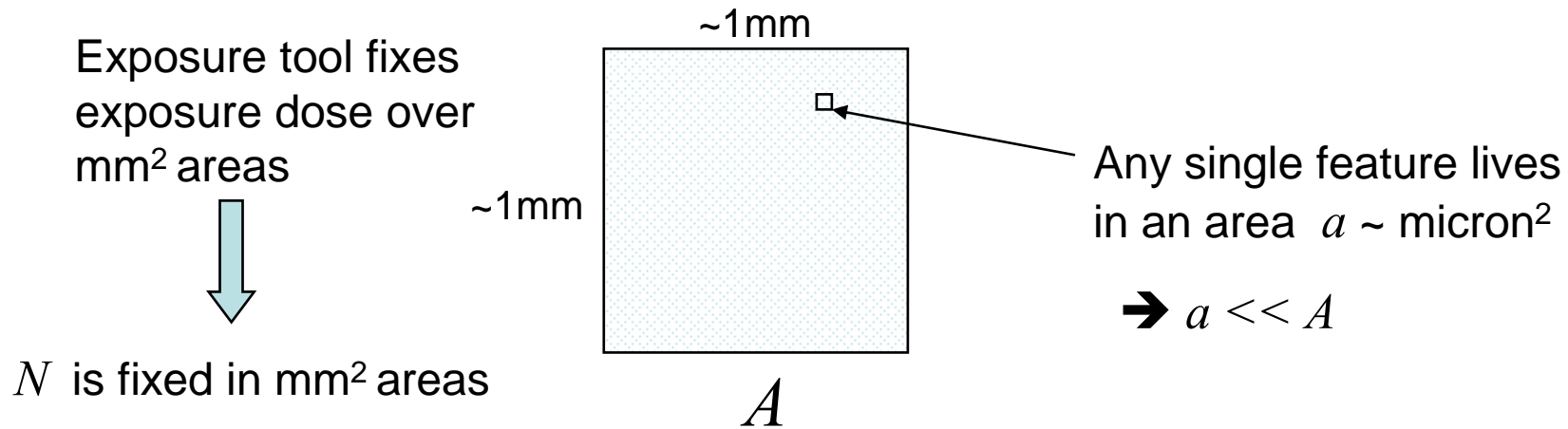


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6

Probability distribution for absorbing a photon and releasing an acid ~ Image intensity



Probability for releasing a fixed number of acids $P(\vec{r}_1, \vec{r}_2, \dots, \vec{r}_N) = P(\vec{r}_1)P(\vec{r}_2) \dots P(\vec{r}_N)$

Probability of getting n acids in area $a \ll A$ $P_n(a \ll A) = \text{Poisson}$
“Shot noise for free”

Consistent with quantum mechanics

→ Interference patterns build up one absorption at a time

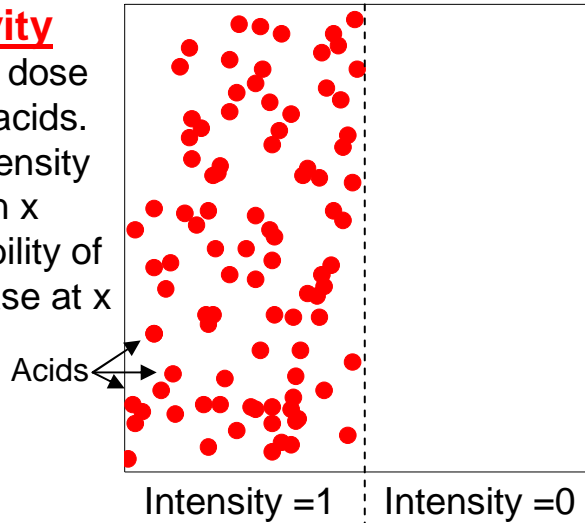
Even with the net number of acids fixed on the macroscale get “shot noise” on the microscale.

LER Model → RLS Model

Gallatin SPIE 2005

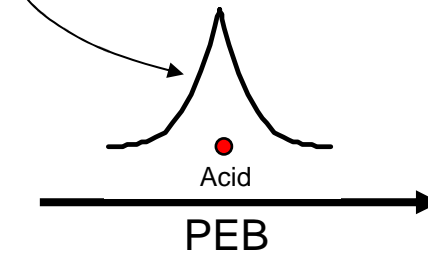
Sensitivity
 Exposure dose releases acids.
 Image intensity at position x
 → Probability of acid release at x

2D Illustration

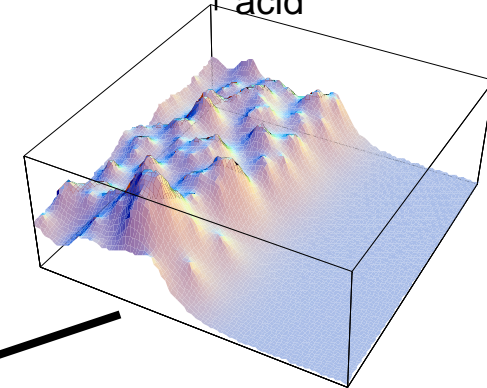


Resolution

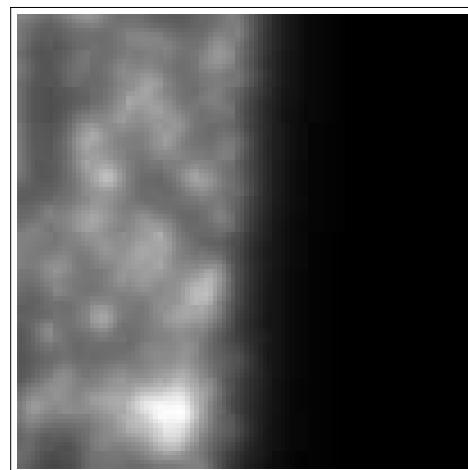
Diffusion/deprotection
 "blur" develops around
 each acid during PEB



Net Deprotection
 Density = Sum of
 "blurs" around each
 acid



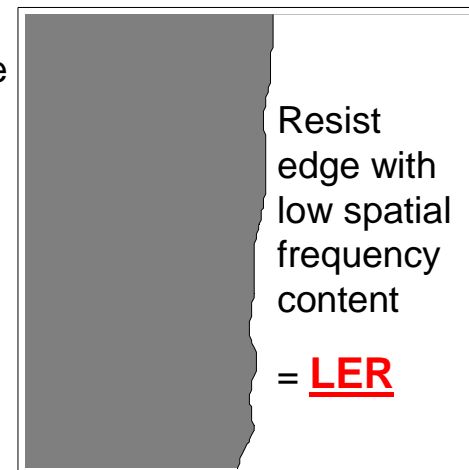
Grayscale plot
 net deprotection
 density



Resist edge position
 occurs at a fixed value
 of deprotection
 ~Critical Ionization
 Model

Development

Burns, et.al., JVST B 2002



Exposure

$\rho_{PAG}(\vec{r}, t)$ = PAG density at position \vec{r} at time t

$$\rho_{PAG}(\vec{r}, t) = \rho_{PAG}(\vec{r}, 0) - \rho_{Acid}(\vec{r}, t)$$

$$\frac{\partial \rho_{Acid}(\vec{r}, t)}{\partial t} = \alpha Q \nu I(\vec{r}) \rho_{PAG}(\vec{r}, t) = \alpha Q \nu I(\vec{r}) (\rho_{PAG}(\vec{r}, 0) - \rho_{Acid}(\vec{r}, t))$$

α = resist absorptivity ($\exp[-\alpha T]$ = transmitted intensity, T = resist thickness)

Q = "Quantum Efficiency" = # acids generated/absorbed photon.

ν = photon - PAG interaction volume (Only PAGs within volume ν surrounding the position of absorption can be affected)

$I(\vec{r}, t)$ = Image intensity (# photons/(area \times time))

$$\text{Solution : } \rho_{Acid}(\vec{r}, t) = \rho_{PAG}(\vec{r}, 0) (1 - \exp[-\alpha Q \nu I(\vec{r}) t]) = \rho_{PAG}(\vec{r}, 0) (1 - \exp[-\alpha Q \nu E(\vec{r})])$$

$E(\vec{r}) = I(\vec{r}) t$ = Dose (# photons/area)

$\alpha Q \nu$ = Dill C (area/# photons) $\Rightarrow 1/C = \text{Saturation Dose} = E_{sat}$ (# photons/area)

Exposure Statistics

Previous slide → Exposure is deterministic. **IT IS NOT**

Quantum Mechanics → Probability of photon absorption ~ Image Intensity

$\rho_{Acid}(\vec{r}, t)$ should be interpreted as a probability

Probability of a PAG to release an acid at position $\vec{r} = (1 - e^{-CE(\vec{r})})$

Probability of a PAG not to release an acid at position $\vec{r} = e^{-CE(\vec{r})}$

Let $a = 1 \Leftrightarrow$ acid released

$a = 0 \Leftrightarrow$ acid NOT released

Probability distribution for an acid to be generated at \vec{r}

$$P_{acid}(\vec{r}, a) = \delta_{a,1}(1 - e^{-CE(\vec{r})}) + \delta_{a,0}e^{-CE(\vec{r})}$$

Net probability distribution

$$P_{acid}^{net}(\vec{r}_1, a_1, \vec{r}_2, a_2, \dots, \vec{r}_N, a_N) = P_{acid}(\vec{r}_1, a_1)P_{acid}(\vec{r}_2, a_2) \cdots P_{acid}(\vec{r}_N, a_N)$$

Need to combine the acid release distribution with the PAG location probability distribution

Consider N PAG molecules uniformly distributed throughout the resist volume

Each PAG can be anywhere with volume V

$$\Rightarrow \text{Probability distribution for one PAG} = \frac{1}{V}$$

$$\Rightarrow \text{Joint probability distribution for all } N \text{ PAG's} = P_{PAG} = V^{-N} = (AT)^{-N}$$

N = the total number of PAG molecules loaded into the resist volume $V = AT$

$$\Rightarrow \rho_{PAG}(\vec{r}, 0) = \frac{N}{V} = \frac{N}{AT}$$

LER Model

Result:
$$\sigma_{LER} = \sqrt{\left(\frac{1}{\rho_{PAG}}\right)\left(\frac{1}{\alpha Q v}\right)^2 \frac{\int_V d^3 r' \rho_D (\vec{r}_s - \vec{r}')^2 (1 - \exp[-\alpha Q v E(\vec{r}')] - \frac{\rho_{Base}}{\rho_{PAG}})}{\left(\int_V d^3 r' \rho_D (\vec{r}_s - \vec{r}') \partial_{\perp} E(\vec{r}') \exp[-\alpha Q v E(\vec{r}')]\right)^2}}$$

Put all the pieces together....do the math to get **approximate** scaling law.....

$$\sigma_{LER} \approx c \left(\frac{I}{\partial I}\right)_{edge} \sqrt{\frac{1}{\rho_{PAG} \alpha Q v E_{size} R^3}}$$

↑ LER ↑ Constant ↑ Dose ↑ "Blur"

} **RLS Tradeoff**

I = Image Intensity

$E = I \times t_{\text{exposure}}$ = Dose

α = Absorptivity

Q = Quantum Efficiency

$R = \sqrt{Dt}$ = PEB Diffusion Range

 ↳ **Intrinsic Resist "Blur"**

v = Photon - Acid interaction volume

ρ_{PAG} = #PAGs/volume

Also get...

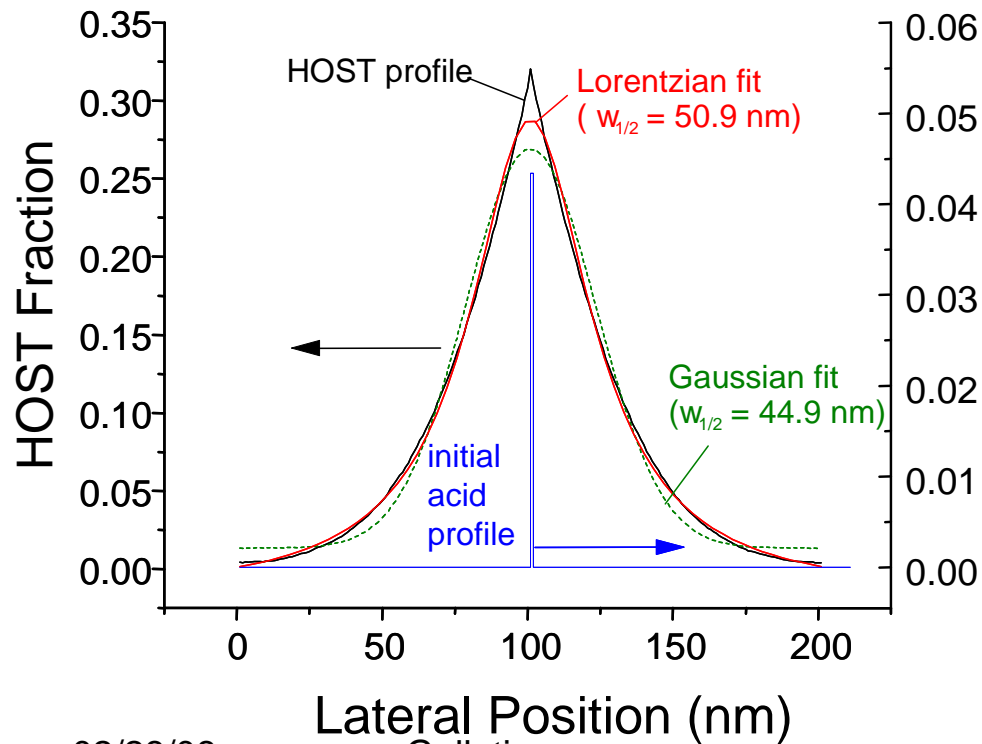
- The explicit analytic form for the deprotection distribution around a released acid.
- The spatial frequency content (on average) of the roughness.

Evaluate 1D result

- Matches full numerical simulation Hinsberg, et. al, SPIE 03
- And experimental shape Hoffnagle, Opt. Letts. 02

Numerical Chemical Kinetics Result

1D Simulation

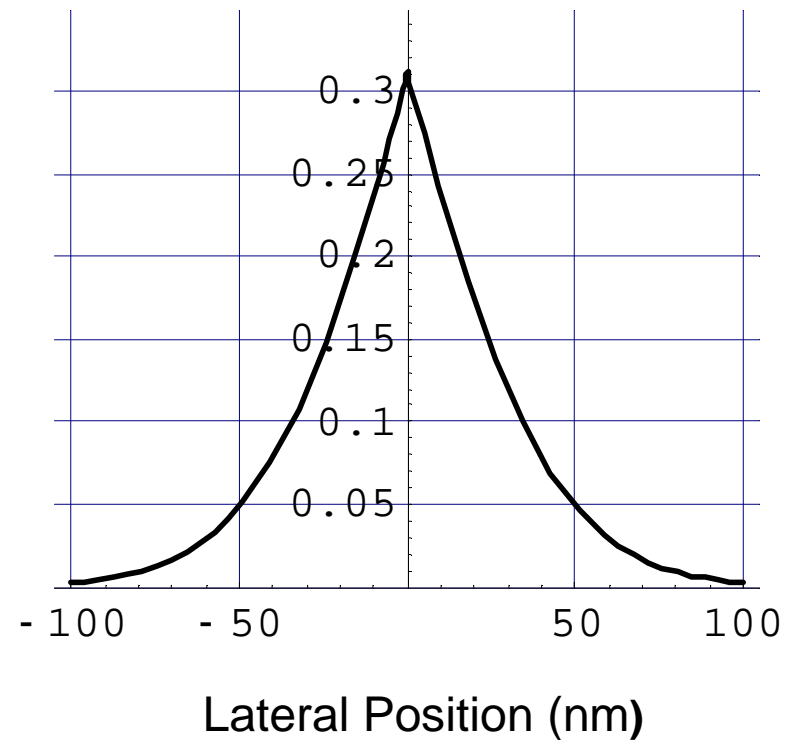


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1D Analytic Form

~ Area integral of full 3D form



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LER Model → Analytical form of the PSD

Formula below is valid for small k . For large k , compute PSD perturbatively for an analytic solution or do the integral numerically.

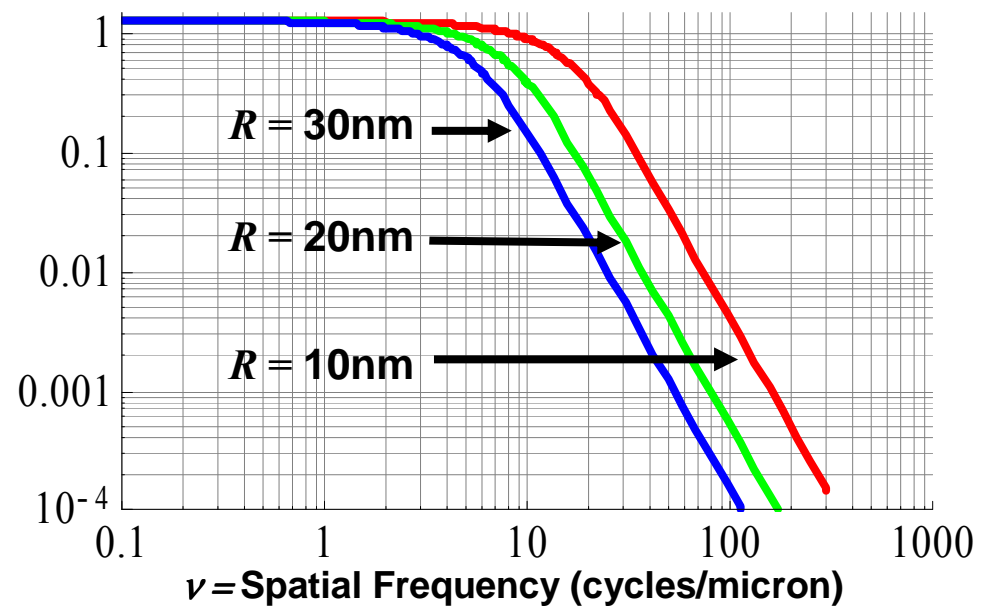
$$PSD(\beta) = norm \times \frac{1}{(R\beta)^3} \left[\begin{aligned} &2(R\beta) e^{-2(R\beta)^2} \left(\sqrt{2\pi} - 2\sqrt{\pi} e^{(R\beta)^2} \right) \\ &+ 2\pi(1 - 2(R\beta)^2) erf(R\beta) \\ &+ \pi(4(R\beta)^2 - 1) erf(\sqrt{2}R\beta) \end{aligned} \right]$$

Normalization factor $\sim \sigma_{LER}^2$

PSD "shape": Depends only on $R\beta = R2\pi\nu$

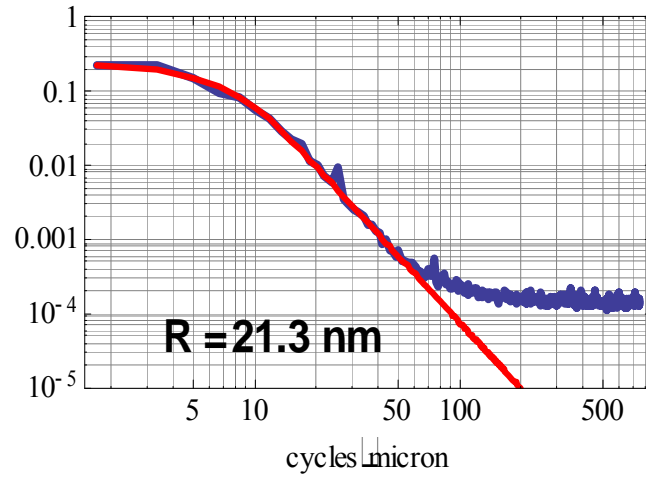
Can determine resist parameters from roughness data

- rms roughness $\rightarrow \sigma_{LER} \rightarrow norm$
- Intrinsic resist "blur" R is determined by fitting the analytic PSD "shape" to $|FFT(data)|^2 / norm$



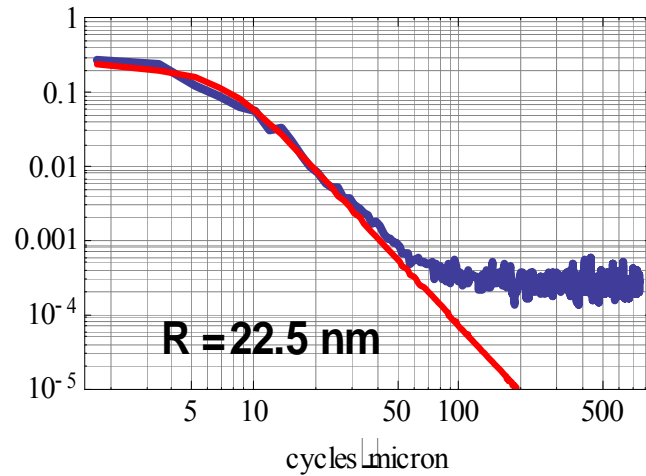
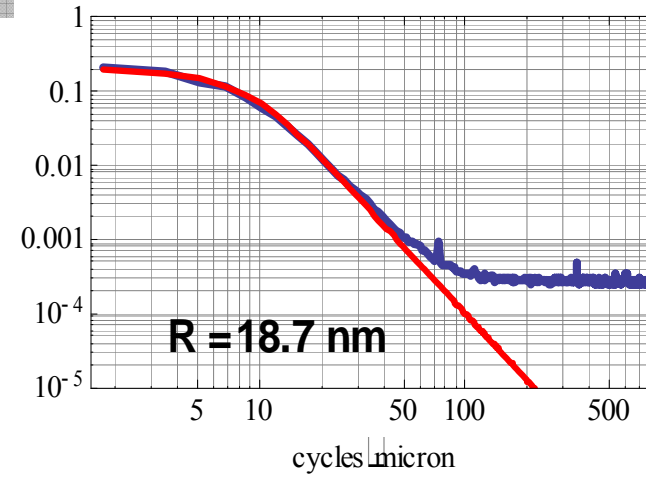
**5435
EUV2D**

Lowest Dose

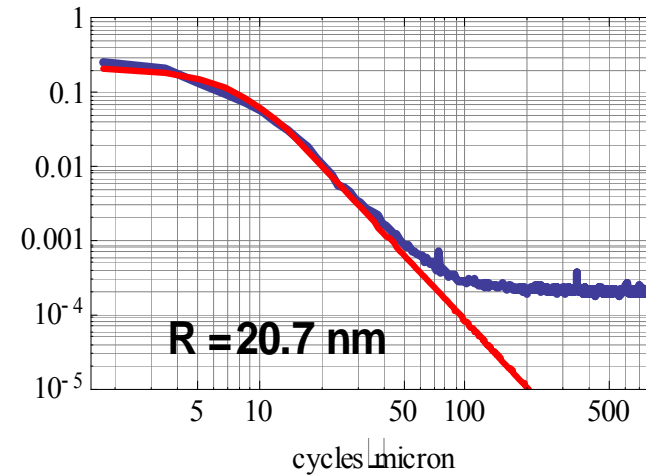


60 nm

Highest Dose

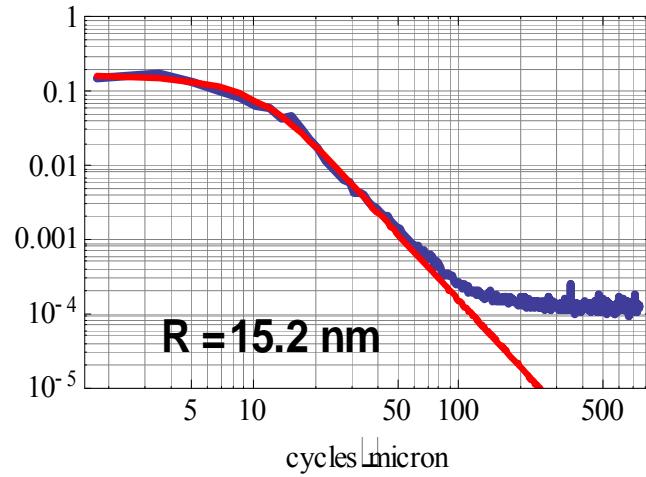


50 nm



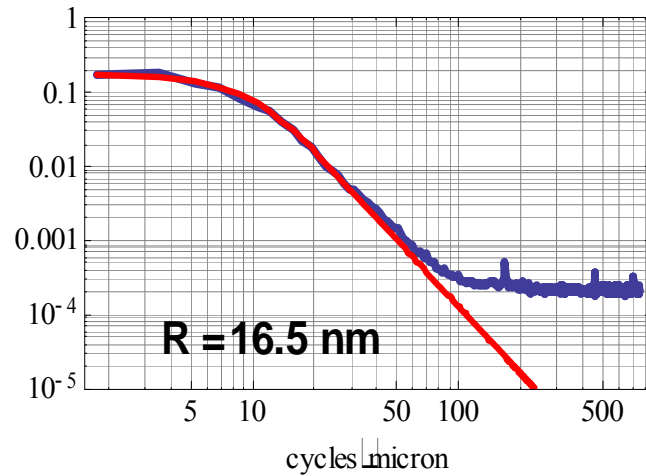
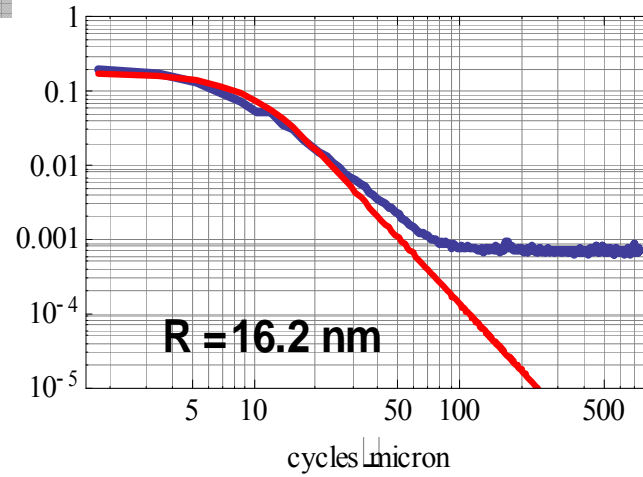
**5271
MET2D**

Lowest Dose

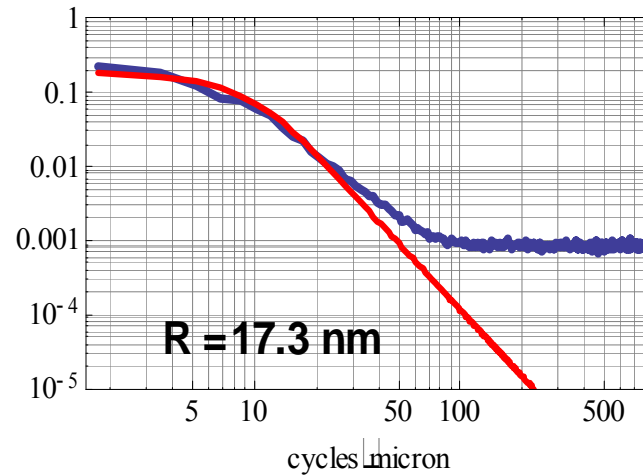


60 nm

Highest Dose



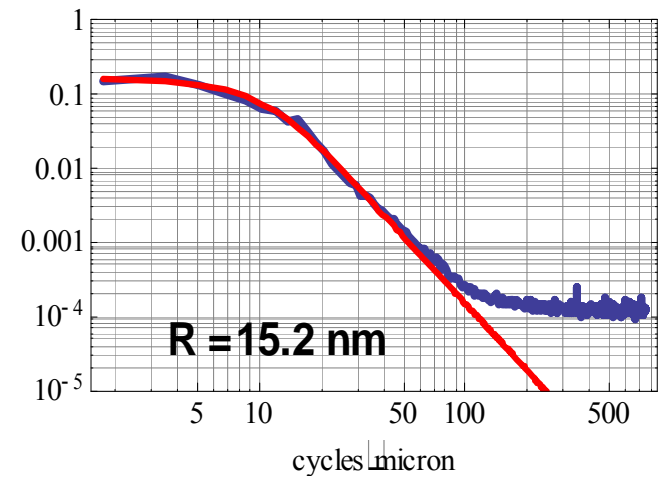
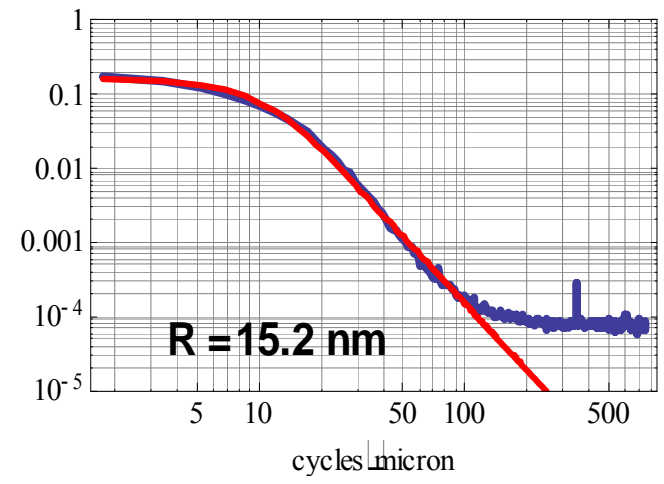
50 nm



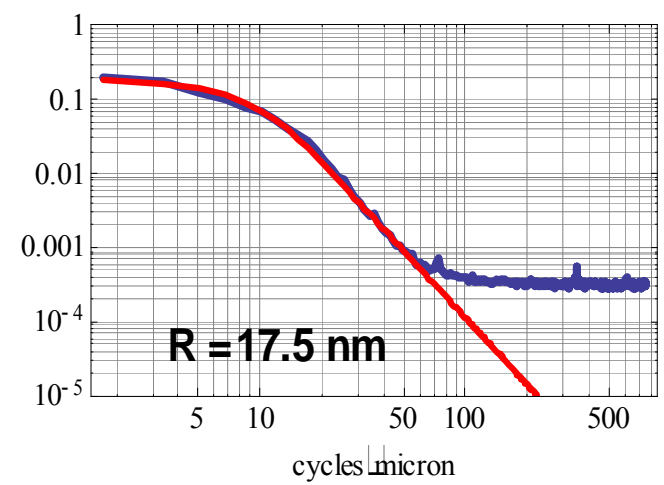
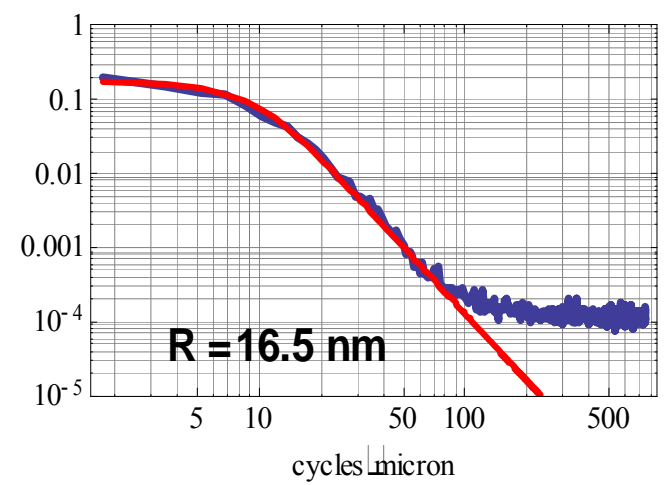
5496

Lowest Dose

Highest Dose



60 nm

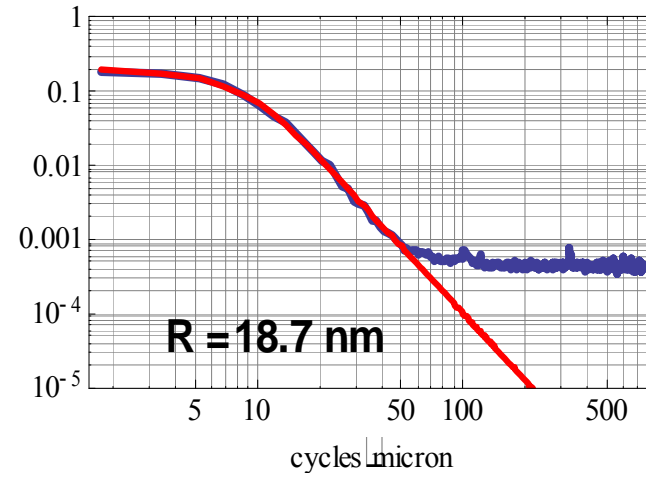
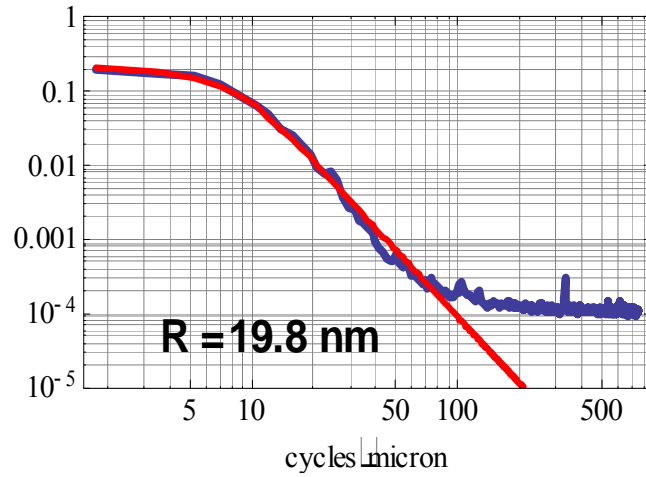


50 nm

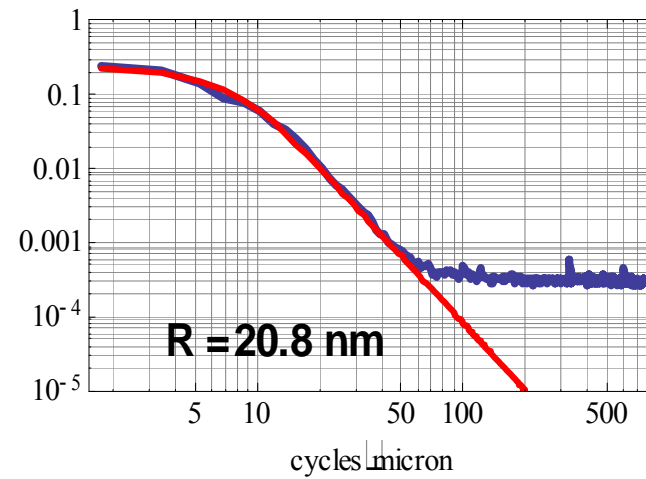
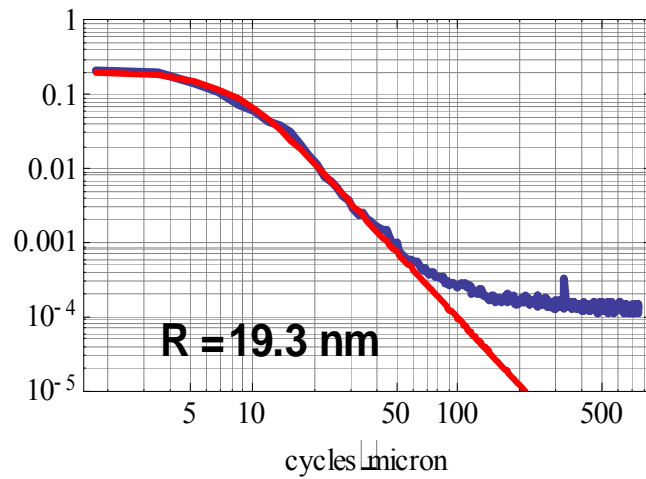
EH

Lowest Dose

Highest Dose



60 nm



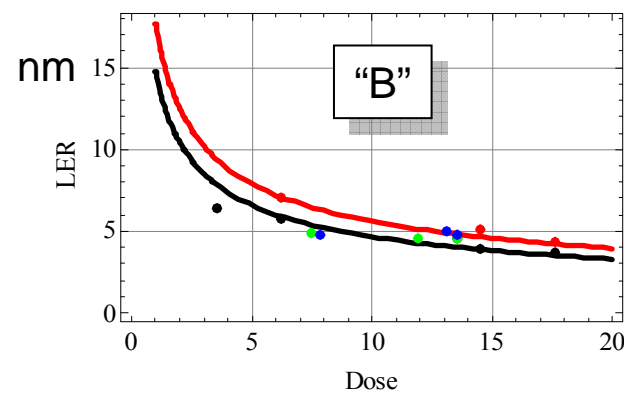
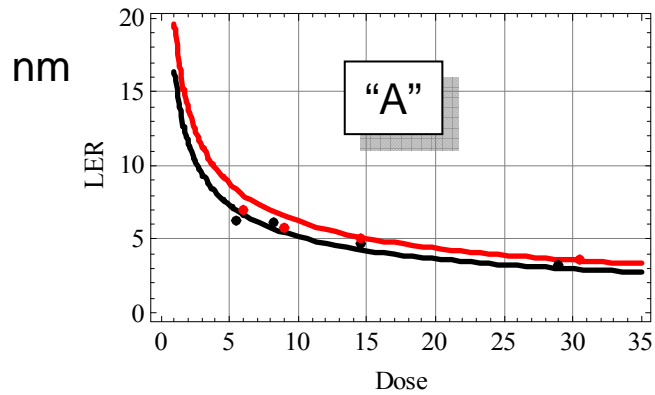
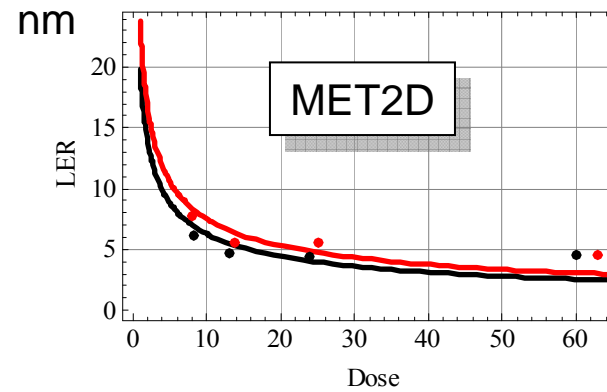
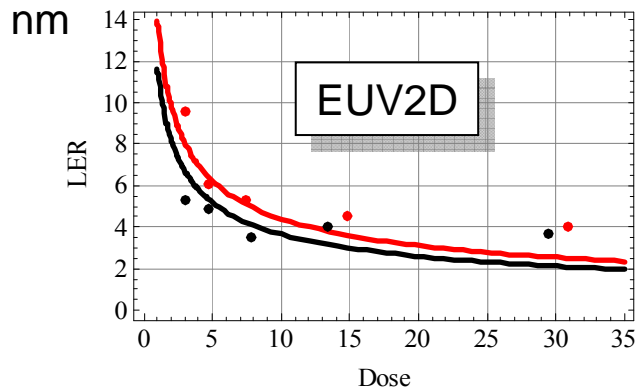
50 nm

LER Data Compared to the Scaling Law

$$\sigma_{LER} \approx c \frac{1}{ILS} \sqrt{\frac{1}{\rho_{PAG} \alpha Q v E_{size} R^3}}$$

$$c \approx 2$$

Red = 50 nm dense L/S
 Black = 60 nm dense L/S
 Dots = data, Curve = model using measured values of ILS, PAG density, Dill-C, Dose, Blur,....



LER Data Compared to the Scaling Law with Saturation Effects Included

$$\sigma_{LER} \approx c \left(\frac{I}{\partial I} \right)_{edge} \sqrt{\frac{1}{\rho_{PAG} \alpha Q v E_{size} R^3 e^{-\alpha Q v E_{size}}}}$$

$$c \approx 1.5$$

